

SEMICONDUCTOR INTEGRATED CIRCUIT

☐ was filed on _____ as United States Application
or PCT International Application No. _____, and
was amended on _____ (if applicable).

I hereby claim foreign priority benefits under 35 U.S.C. 119(a)-(d) or 365 (b) of any foreign application(s) for patent or inventor's certificate, or 35 U.S.C. 365(a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below any foreign application for patent or inventor's certificate, or PCT International application having a filing date before that of the application on which priority is claimed:

<u>Country</u>	<u>Category</u>	<u>Application No.</u>	<u>Filing Date</u>	<u>Priority Claim</u>
Japan	Patent	2000-088408	March 28, 2000	Yes

And I hereby appoint Barry N. Young (Reg.No. 27, 774), Timothy W. Lohse (Reg.No. 35, 255), David F. Keinsmith (Reg.No. 40, 050), Stephen E. Reiter (Reg.No. 31, 192), Wayne P. Sobon (Reg.No. 32, 438), Robroy R. Fawcett (Reg. No. 35, 133), Steven R. Sprinkle (Reg.No. 40, 825), William N. Hulsey III (Reg.No. 33, 402), Terrance A. Meador (Reg.No. 30, 298), John Schlicher (Reg. No. 28, 343), June M. Learn (Reg.No. 31, 238), John Oskorep (Reg.No. 41, 234), Timothy N. Ellis (Reg.No. 41, 734), David R. Stevens (Reg.No. 38, 626), William G. Goldman (Reg.No. 42, 590), Derek Westberg (Reg.No. 40, 872), Alan A. Limbach (Reg.No. 39, 749), Edward B. Weller (Reg.No. 37, 468), Ronald L. Yin (Reg.No. 27, 607), and George C. Limbach (Reg.No. 19, 305) each of whose address is Patent Department-HV, 3340 Hillview Avenue, Palo Alto, Calif. 94304, or any one of them, my attorneys with full power of substitution and revocation, to prosecute this application and to transact all business in the Patent & Trademark Office connected therewith, and request that correspondence be directed to Gray Cary Ware & Freidenrich L. L. P., Patent Department-HV, 3340 Hillview Avenue, Palo Alto, California 94304.

I declare further that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

DECLARATION FOR PATENT APPLICATION

I declare further that my mailing address is at c/o
Intellectual Property Division, KABUSHIKI KAISHA TOSHIBA, 1-1 Shibaura
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that my citizenship and residence are as stated below next to my name:

Inventor: (Signature)

Date

Residence

MAR. 19. 2001

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